

HSD119

Silicon Epitaxial Planar Diode for High Speed Switching

REJ03G1309-0100 Rev.1.00 Oct 27, 2005

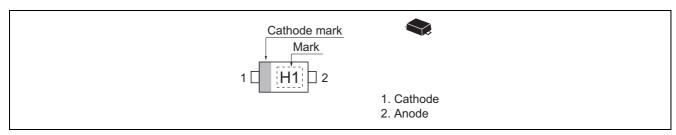
Features

- Low capacitance. (C = 2.0 pF max)
- Short reverse recovery time. $(t_{rr} = 3.0 \text{ ns max})$
- Super small Flat Lead Package (SFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HSD119	H1	SFP	PUSF0002ZB-A (SFP)

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	85	V
Reverse voltage	V_R	80	V
Average rectified current	I ₀	100	mA
Peak forward current	I _{FM}	300	mA
Non-Repetitive peak forward surge current	I _{FSM} *	4	А
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

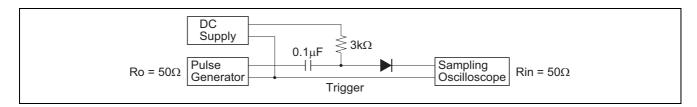
Note: Within 1µs forward surge current.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V_{F1}	_	_	0.8	V	I _F = 10 mA
	V_{F2}	_	_	1.2		I _F = 100 mA
Reverse current	I _R	_	_	0.1	μΑ	V _R = 80 V
Capacitance	С	_	_	2.0	pF	$V_R = 0 V, f = 1 MHz$
Reverse recovery time*1	t _{rr}	_	_	3.0	ns	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, R_L = 50 \Omega$

Note: 1. Reverse recovery time test circuit



Main Characteristics

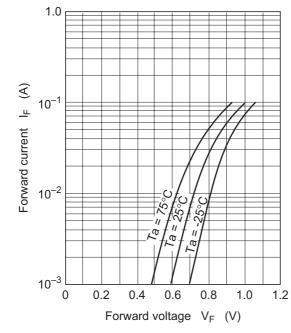


Fig.1 Forward current vs. Forward voltage

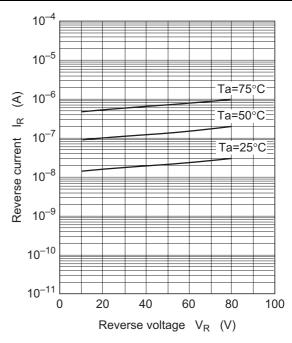
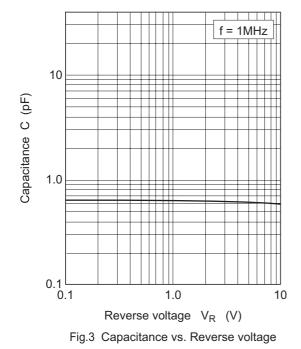
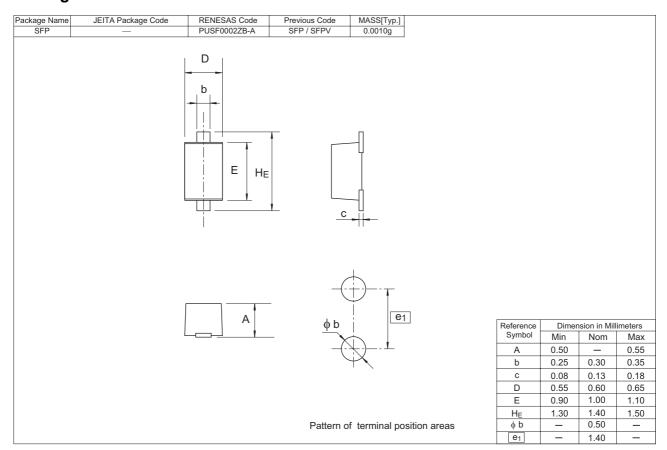


Fig.2 Reverse current vs. Reverse voltage



Package Dimensions



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